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EVAL_500W_5G_PSU

Overview

500W power supply for 5G small cells using 600V CoolMOS™ G7 and CFD7 in DDPAK

Please get in touch with the support center to reserve your board upfront.

The EVAL_500W_5G_PSU demonstrates a power supply from AC (85-305 V_{AC}) to DC (12 V_{DC}) with a rated output power of 500 W. The target applications of this demo board are power supplies for **5G telecom small cells**.

With a height of 27mm only, this PSU comes with high efficiency (96.5% peak efficiency at $230\,V_{AC}$) and fanless cooling enabled by

600V CoolMOS™ superjunction MOSFETs (/cms/en/product/power/mosfet/n-channel/500v-950v/)

housed in the DDPAK package.

Summary of Features

- Featuring top-side cooling 600V CoolMOS™ superjunction MOSFETs
- Fully analog control with ICE3PCS01G, ICE1HS01G and IR11688S
- Fanless cooling design

Benefits

- Low-profile power supply (max. height 27mm)
- Efficiency above 96% at high-line input
- Compact design in 25W/in³ form factor
- Surge protection included
- Wide input voltage range

Potential Applications

- Telecom (/cms/en/applications/communication/telecom-infrastructure/)
- Edge computing



- Server (/cms/en/applications/solutions/power-supplies/server-power-supply/)
- SMPS (/cms/en/applications/solutions/power-supplies/)

List of components

600V CoolMOS™ G7 80mΩ (
IPDD60R080G7 (/cms/en/product/power/mosfet/n-channel/500v950v/ipdd60r080g7/)
) serving as high-frequency MOSFETs in the PFC

600V CoolMOS™ S7 22 mΩ (
IPT60R022S7 (/cms/en/product/power/mosfet/n-channel/500v-950v/ipt60r022s7/))
serving as line-rectification MOSFETs in the PFC

CoolSiC[™] 650V 8A (
 IDH08G65C6 (/cms/en/product/power/diodes-thyristors/coolsic-schottky-diodes/idh08g65c6/)
) serving as high-frequency diodes in the PFC

600V CoolMOS™ CFD7 75 Ω (
IPDD60R075CFD7 (/cms/en/product/power/mosfet/n-channel/500v950v/ipdd60r075cfd7/)
) in the DC-DC primary-side HB

- OptiMOS™ 6 40V 1.3mΩ (
 IQE013N04LM6 (/cms/en/product/power/mosfet/n-channel/iqe013n04lm6/)) in the
 DC-DC secondary-side bridge
- EiceDRIVER™ 1EDN8550 (/cms/en/product/power/gate-driver-ics/1edn8550b/) and 1EDI20N12 (/cms/en/product/power/gate-driver-ics/1edi20n12af/), for driving the PFC and DC-DC CoolMOS™, respectively
- EiceDRIVER™ 2EDN7524G (/cms/en/product/power/gate-driver-ics/2edn7524g/) for driving the OptiMOS™ power MOSFET (IQE013N04LM6)

ICE3PCS01G (/cms/en/product/power/ac-dc-power-conversion/ac-dc-pwm-pfc-

controller/pfc-ccm-continuous-conduction-mode-ics/ice3pcs01g/)
 IC for the PFC control implementation

ICE1HS01G-1 (/cms/en/product/power/ac-dc-power-conversion/ac-dc-pwm-pfc-

controller/llc-resonant-mode-controller/ice1hs01g-1/)
 IC for the DC-DC control implementation

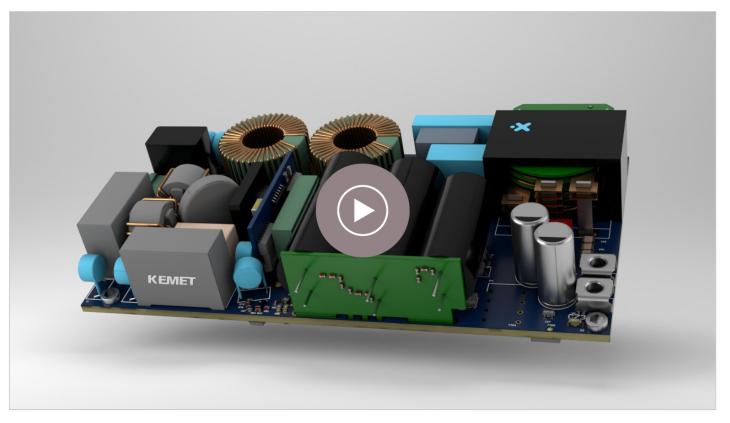
IR11688S (/cms/en/product/power/ac-dc-power-conversion/ac-dc-pwm-pfc-

• controller/synchronous-rectification-ics/ir11688s/)
IC for the secondary-side bridge control implementation

ICE2QR2280G (/cms/en/product/power/ac-dc-power-conversion/ac-dc-integral

power-stage-coolset/quasi-resonant-coolset/ice2qr2280g/)
 for the bias supply implementation





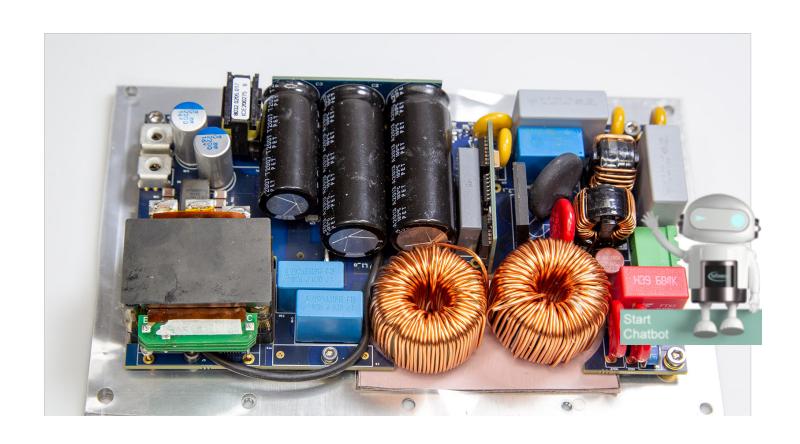
(https://www.infineon.com/cms/media/pss-3dmodels/500w-5g-psu/)







(/cms/en/product/promopages/productregistration/?intc=PSS.P.B.2021)



Parametrics

Parametrics	EVAL_500W_5G_PSU
Input Type	AC
Output Current	42 A
Output Voltage	12 V
P _{out}	500 W
Product Name	EVAL_500W_5G_PSU
Supply Voltage min max	230 V 85 V 305 V
Target Application	SMPS ; Telecom
Topology	Boost; Isolated; LLC; PFC

Documents

> Login (/sec/login? ret=https%3A%2F%2Fwww.infineon.com%2Fcms%2Fen%2Fproduct%2Fevaluation-boards%2Feval_500w_5g_psu%2F%23!documents) to myInfineon to see all documents available

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Data Sheets

